Dual Monostable Multivibrator

The MC14528B is a dual, retriggerable, resettable monostable multivibrator. It may be triggered from either edge of an input pulse, and produces an output pulse over a wide range of widths, the duration of which is determined by the external timing components, $C_{\rm X}$ and $R_{\rm X}$.

Features

- Separate Reset Available
- Diode Protection on All Inputs
- Triggerable from Leading or Trailing Edge Pulse
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- This part should only be used in new designs where the pulse width is $< 10 \, \mu s$

Note: For designs requiring a pulse width $> 10 \mu s$, please see MC14538, which is pin–for–pin compatible

- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- This Device is Pb–Free and is RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to V_{SS})

Rating	Symbol	Value	Unit
DC Supply Voltage Range	V_{DD}	-0.5 to +18.0	V
Input or Output Voltage Range (DC or Transient)	V _{in} , V _{out}	-0.5 to V _{DD} + 0.5	V
Input or Output Current (DC or Transient) per Pin	I _{in} , I _{out}	±10	mA
Power Dissipation, per Package (Note 1)	P _D	500	mW
Ambient Temperature Range	T _A	-55 to +125	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C
Lead Temperature (8–Second Soldering)	TL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Temperature Derating: "D/DW" Packagé: -7.0 mW/°C From 65°C To 125°C This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



ON Semiconductor®

http://onsemi.com

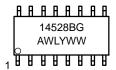


SOIC-16 D SUFFIX CASE 751B

PIN ASSIGNMENT

V _{SS} [1●	16	V_{DD}
C _X 1/R _X 1	2	15	V_{SS}
RESET 1	3	14	$C_X 2/R_X 2$
A1 [4	13	RESET 2
B1 [5	12	A2
Q1 [6	11	B2
Q1 [7	10	Q2
V _{SS} [8	9	Q2

MARKING DIAGRAM



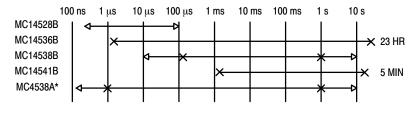
A = Assembly Location WL = Wafer Lot

YY, Y = Year WW, W = Work Week G = Pb-Free Package

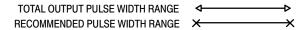
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

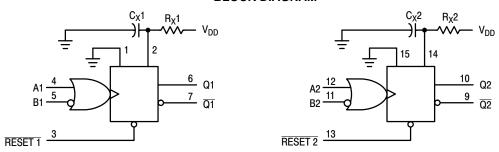
ONE-SHOT SELECTION GUIDE



*LIMITED OPERATING VOLTAGE (2-6 V)



BLOCK DIAGRAM



$$\begin{split} &V_{DD} = PIN\ 16 \\ &V_{SS} = PIN\ 1,\ PIN\ 8,\ PIN\ 15 \\ &R_X\ AND\ C_X\ ARE\ EXTERNAL\ COMPONENTS \end{split}$$

FUNCTION TABLE

	Inputs	Out	puts		
Reset	Α	В	Q	Q	
H H	√ L	H ~	<u>Г</u>	л Л	
H H			Not Triggered Not Triggered		
H H	L, H, <i>\</i> _ L	H L, H, <i>-</i> ∕⁻		ggered ggered	
	X X	X X	L Not Tri	H iggered	

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

				– 55°C 25°C		125	5°C				
Characteristic		Symbol	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage "0 V _{in} = V _{DD} or 0)" Level	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
"1" Level V _{in} = 0 or V _{DD}		V _{OH}	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage "0 (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc))" Level	V _{IL}	5.0 10 15	- - -	1.5 3.0 4.0	- - -	2.25 4.50 6.75	1.5 3.0 4.0	- - -	1.5 3.0 4.0	Vdc
"1 (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc)	" Level	V _{IH}	5.0 10 15	3.5 7.0 11	- - -	3.5 7.0 11	2.75 5.50 8.25	1 1 1	3.5 7.0 11	- - -	Vdc
Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc)	Source	ГОН	5.0 5.0 10 15	-1.2 -0.64 -1.6 -4.2	- - -	-1.0 -0.51 -1.3 -3.4	-1.7 -0.88 -2.25 -8.8	1 1 1	-0.7 -0.36 -0.9 -2.4		mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I _{OL}	5.0 10 15	0.64 1.6 4.2	- - -	0.51 1.3 3.4	0.88 2.25 8.8	- - -	0.36 0.9 2.4	- - -	mAdc
Input Current		l _{in}	15	_	±0.1	-	±0.00001	±0.1	-	±1.0	μAdc
Input Capacitance (V _{in} = 0)		C _{in}	-	-	-	-	5.0	7.5	_	-	pF
Quiescent Current (Per Package)		I _{DD}	5.0 10 15	- - -	5.0 10 20	- - -	0.005 0.010 0.015	5.0 10 20	- - -	150 300 600	μAdc
Total Supply Current at an exload Capacitance (C _L) and a ternal timing capacitance (C _Y the formula. (Note 3)	t ex-	Ι _Τ	-	wher	e: I _T in μΑ	R _X C ₃ per circu	$C_L + 0.36C_X$) $\chi(V_{DD}^{-2})^2f] x$ $\chi(I), C_L and C_L in kHz is inp$	10 ^{−3} ; _X in pF, R	X in mego	hms,	μAdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

3. The formulas given are for the typical characteristics only at 25°C.

SWITCHING CHARACTERISTICS ($C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$) (Note 4)

Characteristic	Symbol	C _X pF	R _X kΩ	V _{DD} Vdc	Min	Typ (Note 5)	Max	Unit
Output Rise and Fall Time $t_{TLH}, t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ $t_{TLH}, t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ $t_{TLH}, t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$	t _{TLH} , t _{THL}	-	-	5.0 10 15	- - -	100 50 40	200 100 80	ns
Turn–Off, Turn–On Delay Time — A or B to Q or \overline{Q} t _{PLH} , t _{PHL} = (1.7 ns/pF) C _L + 240 ns t _{PLH} , t _{PHL} = (0.66 ns/pF) C _L + 87 ns t _{PLH} , t _{PHL} = (0.5 ns/pF) C _L + 65 ns	t _{PLH} , t _{PHL}	15	5.0	5.0 10 15	- - -	325 120 90	650 240 180	ns
Turn–Off, Turn–On Delay Time — A or B to Q or \overline{Q} t _{PLH} , t _{PHL} = (1.7 ns/pF) C _L + 620 ns t _{PLH} , t _{PHL} = (0.66 ns/pF) C _L + 257 ns t _{PLH} , t _{PHL} = (0.5 ns/pF) C _L + 185 ns	t _{PLH} , t _{PHL}	1000	10	5.0 10 15	- - -	705 290 210		ns
Input Pulse Width — A or B	t _{WH}	15	5.0	5.0 10 15	150 75 55	70 30 30		ns
	t _{WL}	1000	10	5.0 10 15	- - -	70 30 30	- - -	ns
Output Pulse Width — Q or \overline{Q} (For $C_X < 0.01 \mu F$ use graph for appropriate V_{DD} level.)	t _W	15	5.0	5.0 10 15	- - -	550 350 300	- - -	ns
Output Pulse Width — Q or \overline{Q} (For $C_X > 0.01 \mu F$ use formula: $t_W = 0.2 R_X C_X Ln [V_{DD} - V_{SS}])$ (Note 6)	t _W	10,000	10	5.0 10 15	15 10 15	30 50 55	45 90 95	μs
Pulse Width Match between Circuits in the same package	t1 – t2	10,000	10	5.0 10 15	- - -	6.0 8.0 8.0	25 35 35	%
Reset Propagation Delay — Reset to Q or Q	t _{PLH} , t _{PHL}	15	5.0	5.0 10 15	- - -	325 90 60	600 225 170	ns
		1000	10	5.0 10 15	- - -	1000 300 250	- - -	ns
Retrigger Time	t _{rr}	15	5.0	5.0 10 15	0 0 0	- - -	- - -	ns
		1000	10	5.0 10 15	0 0 0	- - -	- - -	ns
External Timing Resistance	R _X	-	-	-	5.0	_	1000	kΩ
External Timing Capacitance	C _X	_	ı	_	No Limits (Note 7)			μF

The formulas given are for the typical characteristics only at 25°C.
 Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.
 If C_X > 15 μF, Use Discharge Protection Diode D_X, per Figure 9.
 R_Xis in Ω, C_X is in farads, V_{DD} and V_{SS} in volts, PW_{out} in seconds.

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14528BDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14528BDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NLV14528BDR2G*	SOIC-16 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

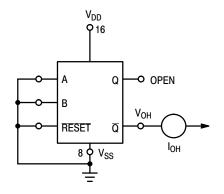


Figure 1. Output Source Current Test Circuit

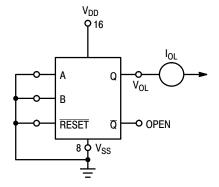


Figure 2. Output Sink Current Test Circuit

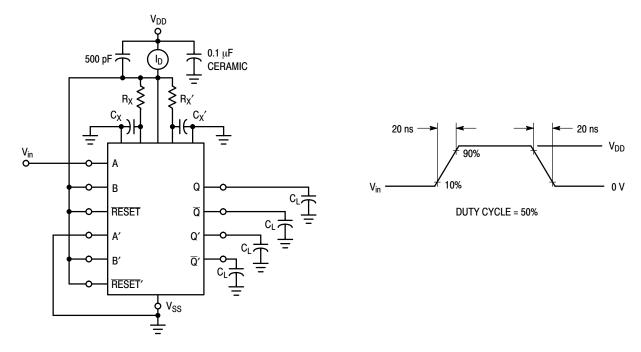
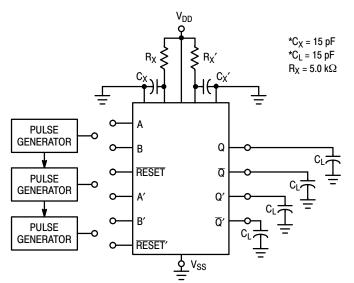


Figure 3. Power Dissipation Test Circuit and Waveforms



INPUT CONNECTIONS

Characteristics	Reset	Α	В
$t_{PLH},t_{PHL},t_{TLH},t_{THL},t_{W}$	V_{DD}	PG1	V_{DD}
$t_{PLH},t_{PHL},t_{TLH},t_{THL},t_{W}$	V_{DD}	V _{SS}	PG2
$t_{PLH(R)}, t_{PHL(R)}, t_{W}$	PG3	PG1	PG2

*Includes capacitance of probes, wiring, and fixture parasitic.

NOTE: AC test waveforms for PG1, PG2, and PG3 on next page.

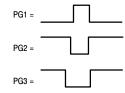


Figure 4. AC Test Circuit

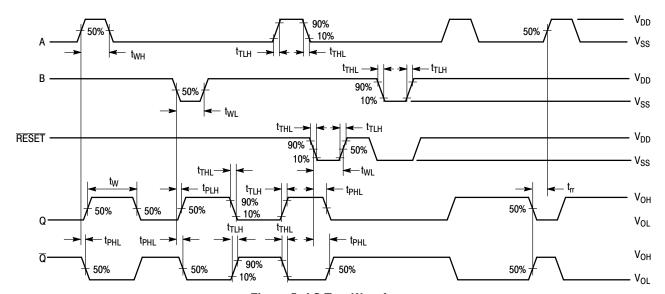


Figure 5. AC Test Waveforms

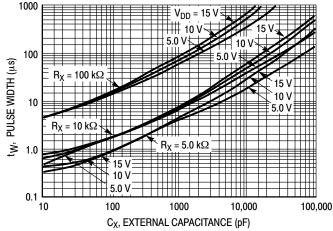


Figure 6. Pulse Width versus C_X

TYPICAL APPLICATIONS

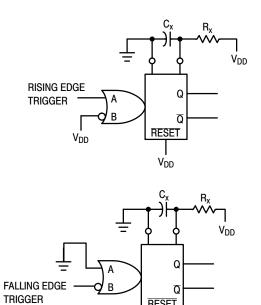


Figure 7. Retriggerable Monostables Circuitry

 V_{DD}

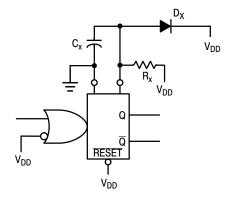


Figure 9. Use of a Diode to Limit Power Down Current Surge

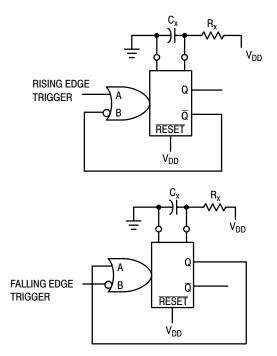


Figure 8. Non-Retriggerable Monostables Circuitry

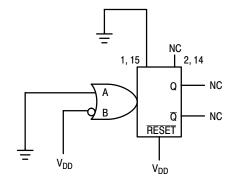


Figure 10. Connection of Unused Sections

MECHANICAL CASE OUTLINE



DATE 29 DEC 2006

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI
- THE NOTION AND TOLETANOING FER ANSI'Y 14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
- PHOI HUSION.

 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

 DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR PROTRUSION

 SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D

 DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES	
DIM	MIN MAX		MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
C	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
7	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

STYLE 1: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13. 14.	COLLECTOR BASE EMITTER NO CONNECTION EMITTER BASE	2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12.	CATHODE CATHODE ANODE NO CONNECTION CATHODE CATHODE NO CONNECTION	STYLE 3: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13. 14.	COLLECTOR, DYE #1 BASE, #1 EMITTER, #1 COLLECTOR, #1 COLLECTOR, #2 BASE, #2 EMITTER, #2 COLLECTOR, #2 COLLECTOR, #3 BASE, #3 EMITTER, #3 COLLECTOR, #3 COLLECTOR, #3 COLLECTOR, #3	STYLE 4: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13.	COLLECTOR, DYE #1 COLLECTOR, #1 COLLECTOR, #2 COLLECTOR, #3 COLLECTOR, #3 COLLECTOR, #4 COLLECTOR, #4 COLLECTOR, #4 EMITTER, #4 BASE, #4 EMITTER, #3 BASE, #2 EMITTER, #2 BASE, #1		FOOTPRINT ×
16.	COLLECTOR	16.	CATHODE	16.	COLLECTOR, #4	16.	EMITTER, #1		^{3X} 40 →
STYLE 5: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13. 14.	DRAIN, DYE #1 DRAIN, #1 DRAIN, #2 DRAIN, #2 DRAIN, #3 DRAIN, #3 DRAIN, #3 DRAIN, #4 GATE, #4 SOURCE, #4 GATE, #2 SOURCE, #3 GATE, #2 SOURCE, #2 GATE, #1 SOURCE, #1	2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13. 14.	CATHODE CATHODE CATHODE CATHODE ANODE ANODE ANODE ANODE ANODE ANODE ANODE	STYLE 7: PIN 1. 2. 3. 4. 5. 6. 7. 8. 9. 10. 11. 12. 13. 14.	SOURCE N-CH COMMON DRAIN (OUTPUT COMMON DRAIN (OUTPUT GATE P-CH COMMON DRAIN (OUTPUT COMMON DRAIN (OUTPUT COMMON DRAIN (OUTPUT SOURCE P-CH SOURCE P-CH COMMON DRAIN (OUTPUT COMMON DRAIN (OUTPUT COMMON DRAIN (OUTPUT GATE N-CH COMMON DRAIN (OUTPUT GATE N-CH COMMON DRAIN (OUTPUT SOURCE N-CH	n n n n n n	16X 0.58	<u> </u>	16x 1.12
									DIMENSIONS: MILLIMETERS

DOCUMENT NUMBER:	98ASB42566B	Electronic versions are uncontrolled except when accessed directly from the Document Reposi Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	SOIC-16		PAGE 1 OF 1			

ON Semiconductor and at a trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT
North American Technical Support:
Voice Mail: 1 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: a Phone: 00421 33 790 2910

Phone: 011 421 33 790 2910 For additional information, please contact your local Sales Representative